

isc N-Channel MOSFET Transistor

FCPF190N65FL1

- FEATURES
- With TO-220F packaging
- · High speed switching
- Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Power supply
- Switching applications

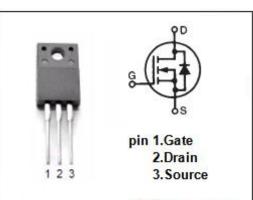
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous;@Tc=25°C	20.6	A
I _{DM}	Drain Current-Single Pulsed	61.8	A
PD	Total Dissipation	39	W
Tj	Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	°C

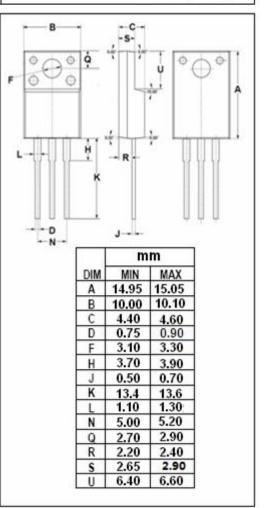
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.2	°C/W

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ELECTRICAL CHARACTERISTICS

$T_{\rm C}\text{=}25^\circ\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =2mA	3		5	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 10A			190	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V			10	μA
VSDF	Diode forward voltage	I _{SD} =10A, V _{GS} = 0 V			1.2	V

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